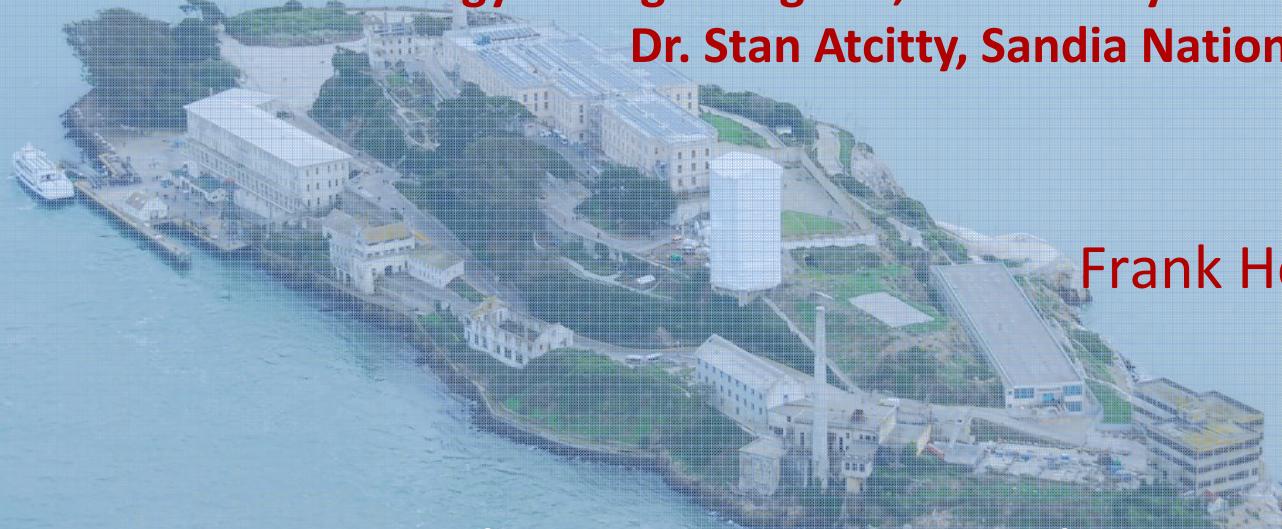


# 2014 DOE OE Energy Storage Program Peer Review

## 60kW Inverter with Built-In Isolation Using GaN Devices (SBIR Phase I – DOE Energy Storage Program, Dr. Imre Gyuk and Technical POC Dr. Stan Atcitty, Sandia National Laboratories)



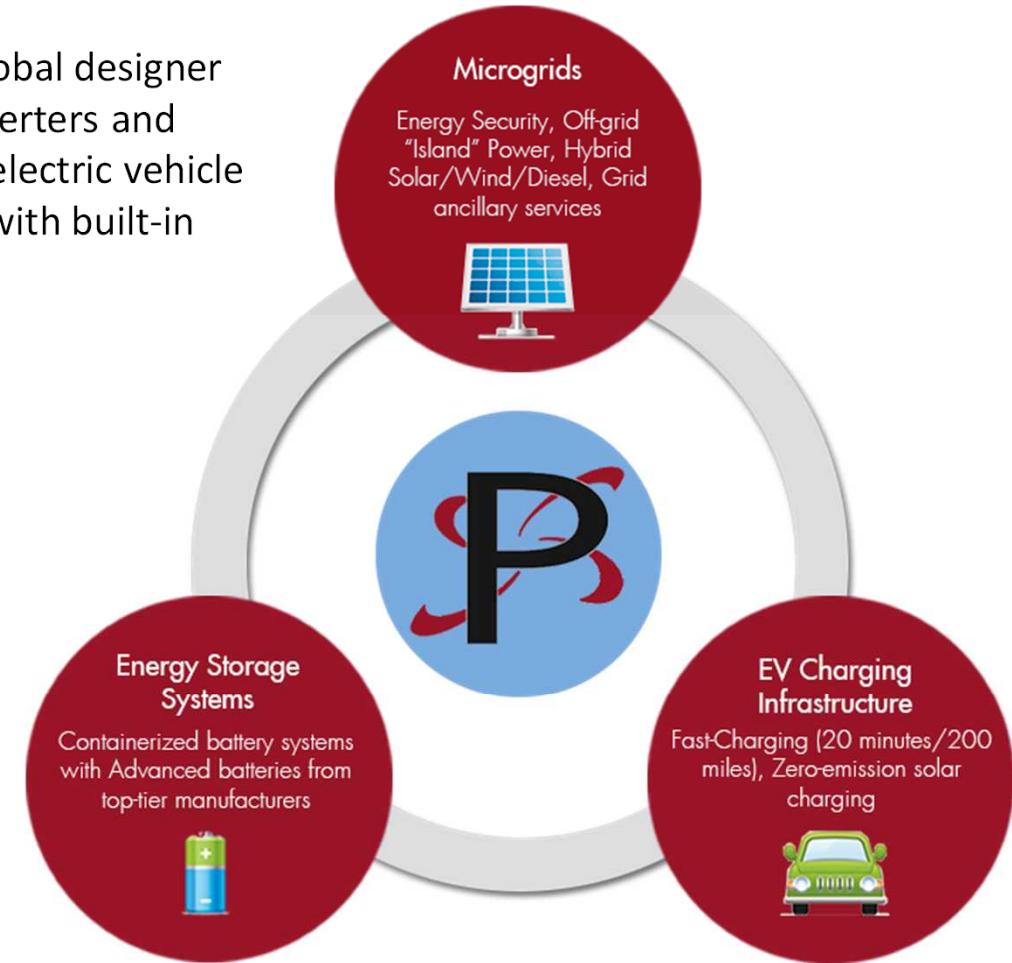
Frank Hoffmann, PhD

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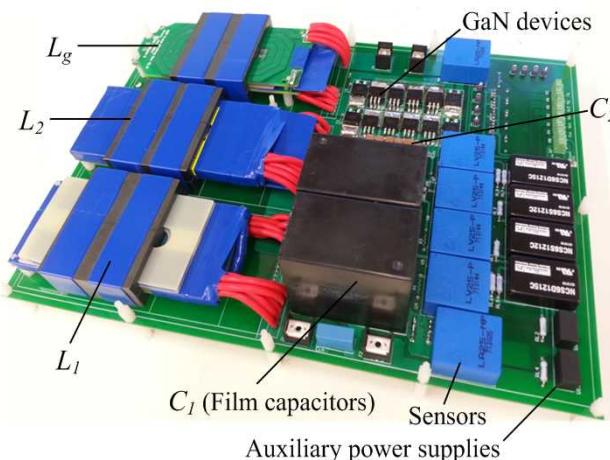
# Project Team: PPS

Princeton Power Systems is a leading global designer and manufacturer of bi-directional converters and energy storage systems for microgrids, electric vehicle (EV) charging, and advanced batteries, with built-in functions for Smart Grid Services.

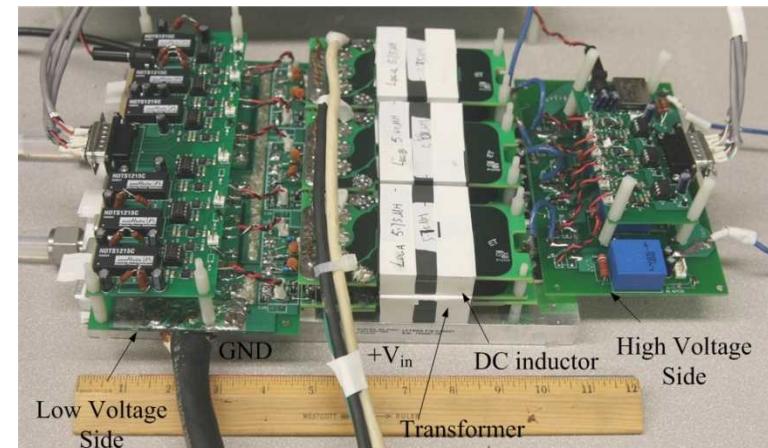


# Project Team: Florida State University/PE Group

**FSU/PE group** has rich experience about WBG devices application in grid-connected PV converters. The group has successfully developed GaN based PV Module-Integrated Converter (MIC) and SiC based high power PV converters for grid-interactive application to achieve high power density and high power efficiency. The high frequency operation performance of GaN and SiC devices has been investigated and evaluated.



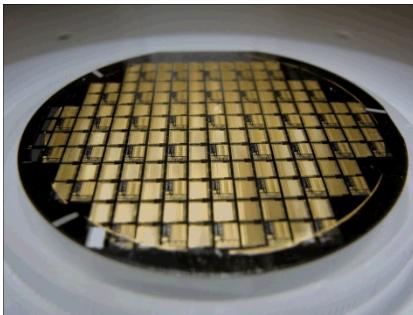
GaN based Module-integrated PV converter



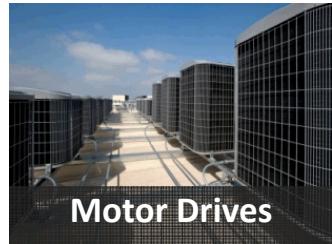
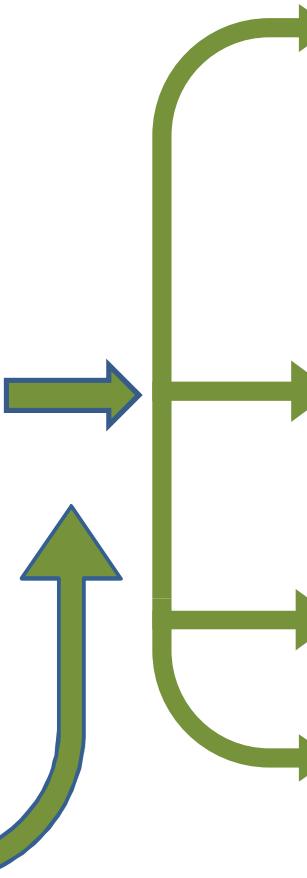
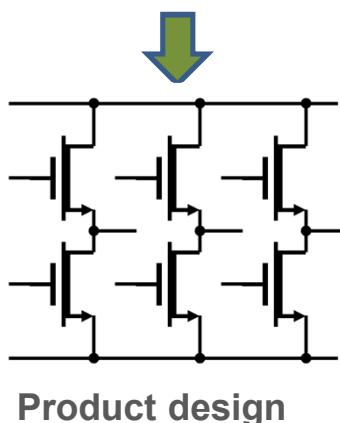
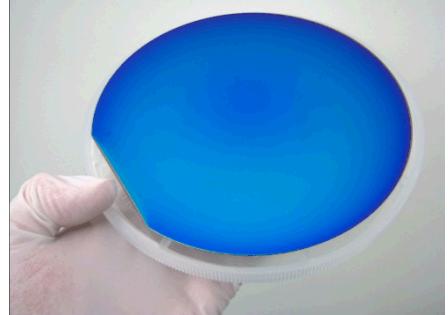
Three-port 5kW grid-tie PV converter

# Project Team: Transphorm – GaN Technology

Device eng & Fab



GaN Epi Technology



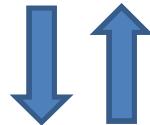
transphorm

PRINCETON  
POWER SYSTEMS  
Clean Power Made Simple™

# Why are we doing this ?

## ○ Technology Development:

- Demonstrate use of Wide-band-gap devices in a real application
- Devices need to be used to become cheaper



Device need to become cheaper to be used

## ○ Product / Application Development

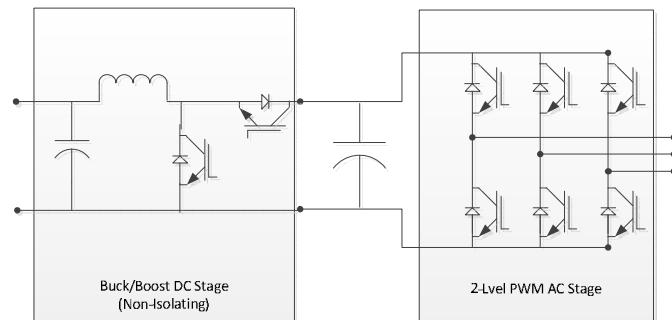
- Reduce cost & size of grid-tied energy storage installations by eliminating bulky grid-side isolation transformers
- Improve efficiency
- Reduce noise (by switching at frequencies outside the audible range)

# Project Steps

- **Phase I : Design 60kW inverter for grid-tied storage applications**
  - Base design on existing PPS 100kW inverter
  - Incorporate DC side isolation by using Dual-Active-Bridges (DAB) using GaN devices
  - Demonstrate DAB functionality
- **Phase II : Build prototype inverter**
  - Modify an existing GTIB inverter with design from Phase I
  - Demonstrate inverter functionality

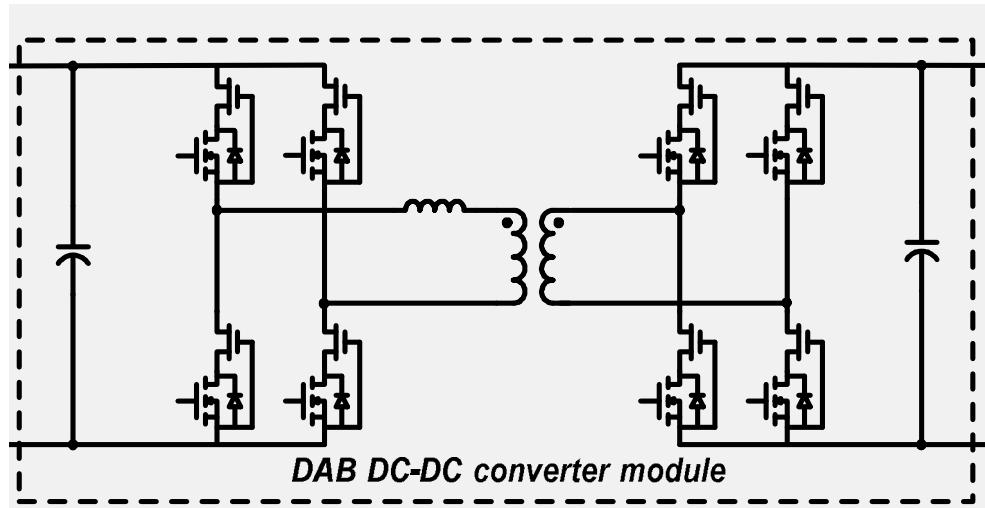
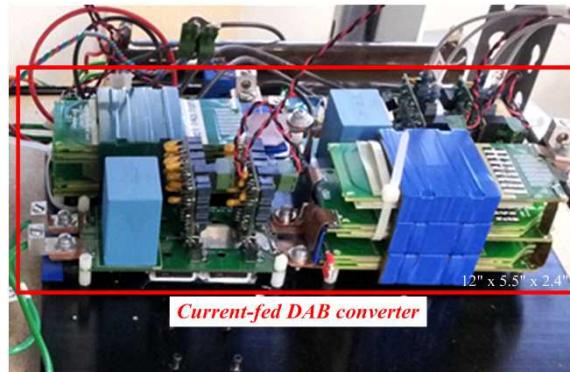
# PPS Grid-Tied Inverter (GTIB-100)

- **100kW grid-tied inverter**
  - Buck/boost DC stage
  - 2-level PWM AC stage
  - 6.5kHz switching frequency
- **Proven technology, used in a number of grid-tied energy storage applications**
  - 'Two-Ups' for Tesla
  - WPD project with GE in the UK
- **No internal isolation -> typically requires external transformer**



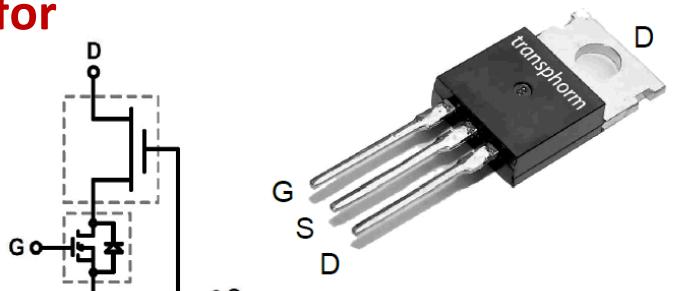
# Dual-Active Bridge DC-DC Converter (FSU)

- **High-frequency switching (proven in lab at FSU)**
  - Drastically decreases size of DC port components
- **Built-in galvanic isolation**
  - Eliminates grid-side transformer, increasing overall system power density



# High Voltage GaN HEMT

- High Switching Frequency : 10x of Si devices for smaller  $Q_g$ ,  $C_{oss}$  &  $Q_{rr}$
- Low  $R_{ds\_on}$ :  $V_B^2/R_{on}=5000$  (40 for Si)
- High temperature operation > 200 C
- Third quadrant operation: Eliminates free-wheeling diode
- Normally-off operation: Safe for high voltage/power



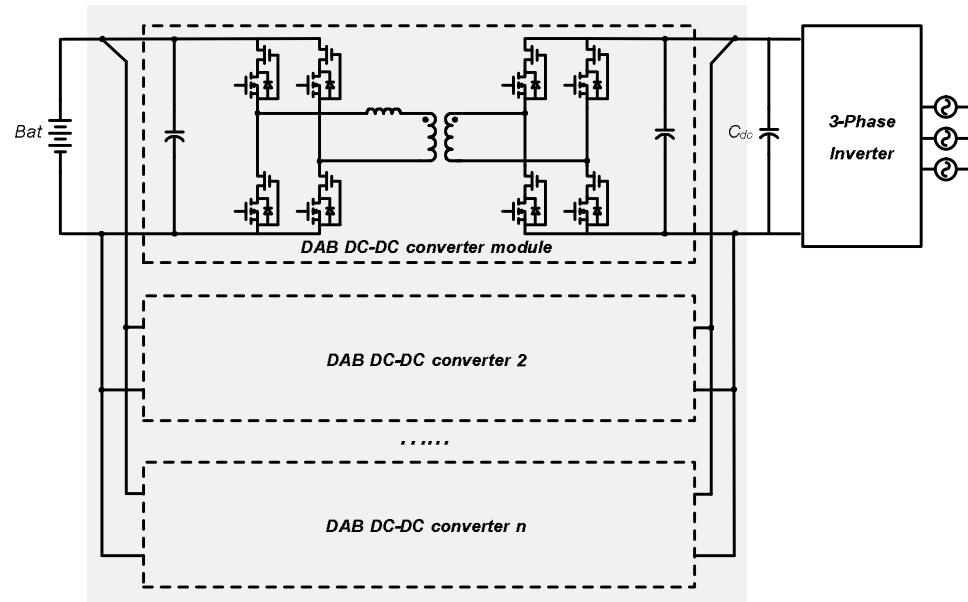
TO-220 Package

Ron	Vds,max	Imax(pulse)	Imax(CW)
mohm	V	A	A
30	900	240	70
Rth	Qg	Qoss	Qrr
°C/W	nC	nC	uC
0.2	25	320	0.35

\*Per switch

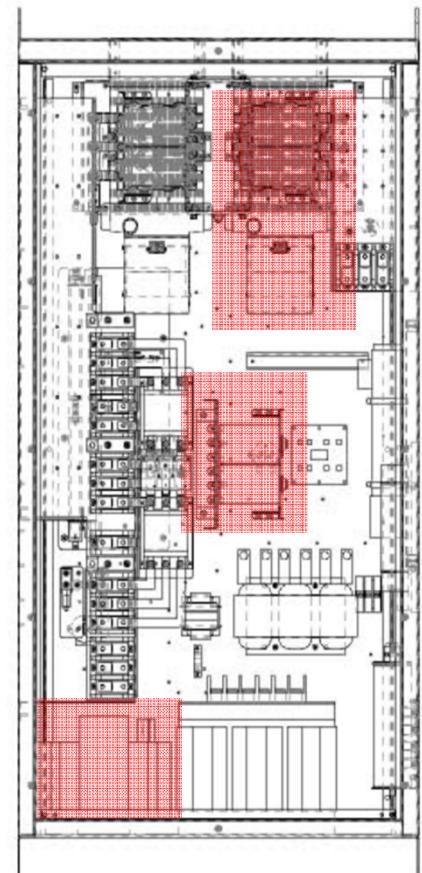
# Target System Architecture

- Keep existing AC stage of GTIB inverter
  - Focusing on main project aspect
- DC stage will consist of multiple DAB converters
  - Allows interleaving, to reduce current ripple
  - Avoids challenges from having to parallel GaN devices



# Design Goals

- DC-DC Stage Efficiency  $\geq 98\%$
- Increase overall power density of installation by 40%
- Reduce overall system cost by 20%
  - Eliminate grid-side isolation transformer  
(-20% total system cost)
  - Reduce cost of reactive components for DC side by estimated 50%  
(-6% total system cost)



Removable DC port Components

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We thank Dr. Imre Gyuk for his funding support and  
Dr. Stan Atcitty for his technical contributions.

# Thank you

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